

SOT-363 Plastic-Encapsulate Transistors

BC847DW DUAL TRANSISTOR (NPN+NPN)

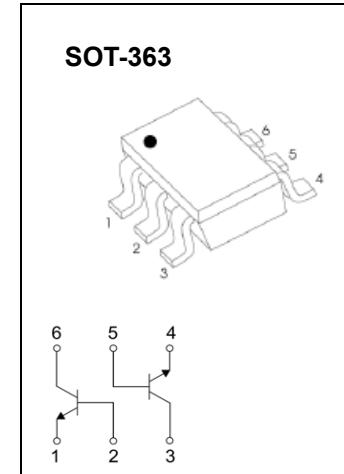
FEATURES

- Two transistors in one package
- Reduces number of components and board space
- No mutual interference between the transistors

MARKING: BC847A 1Et

BC847B 1Ft

BC847C 1Gt

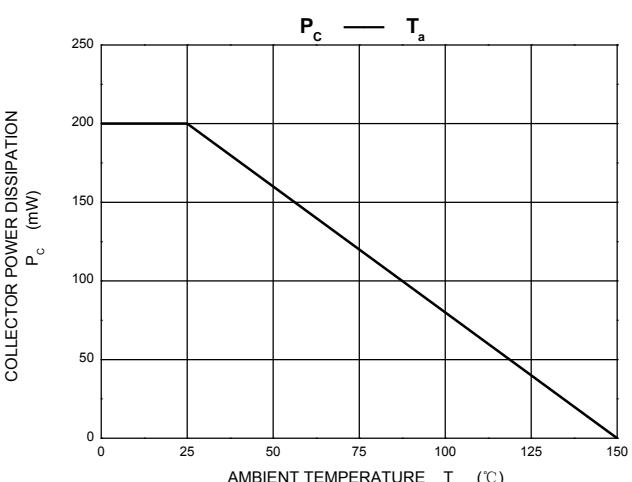
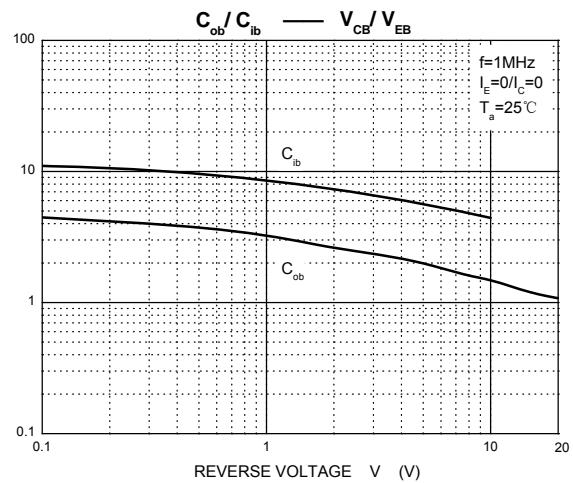
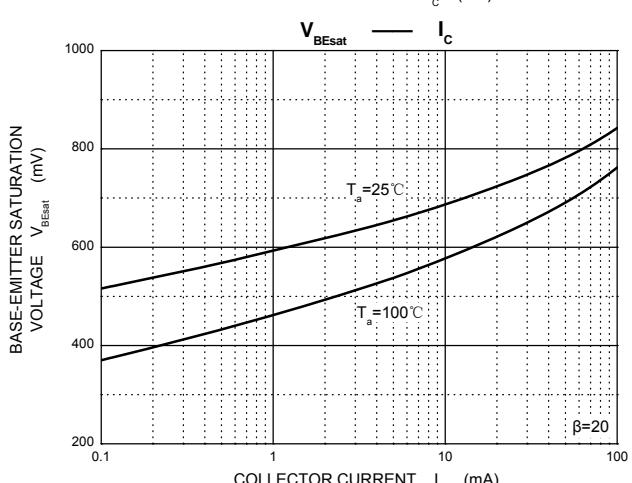
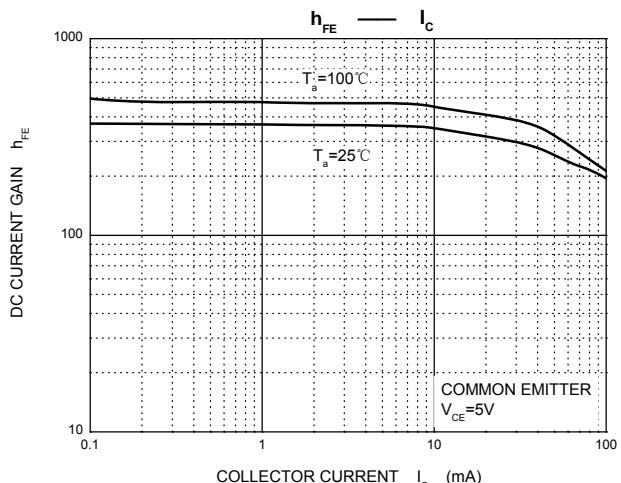
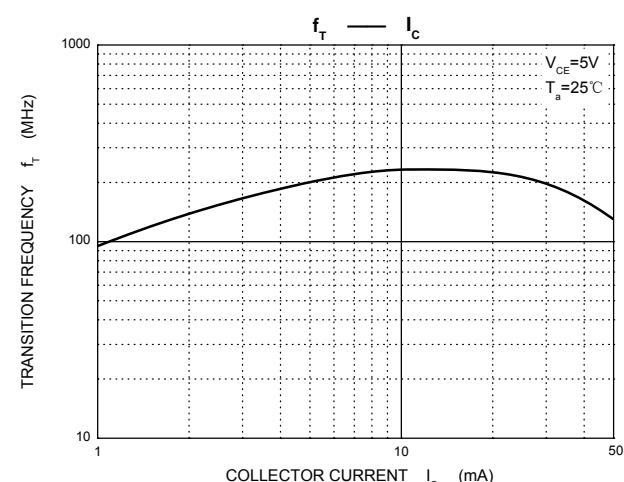
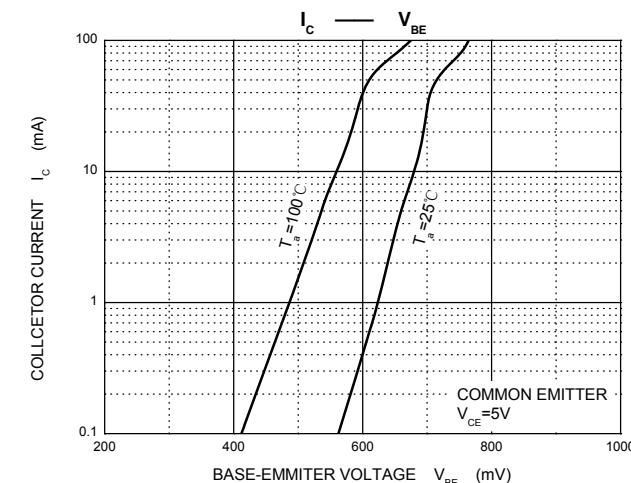
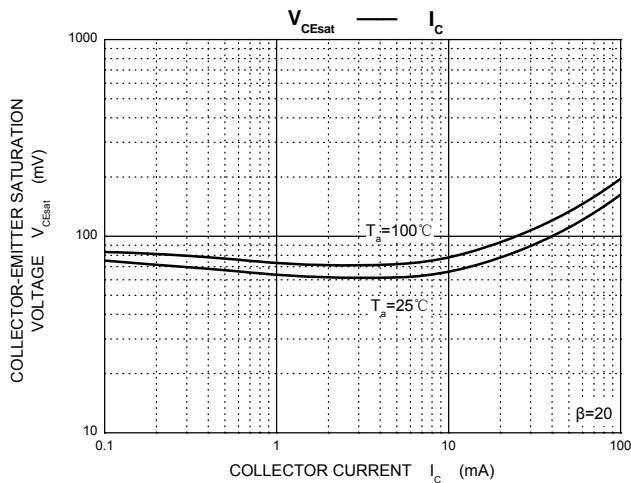
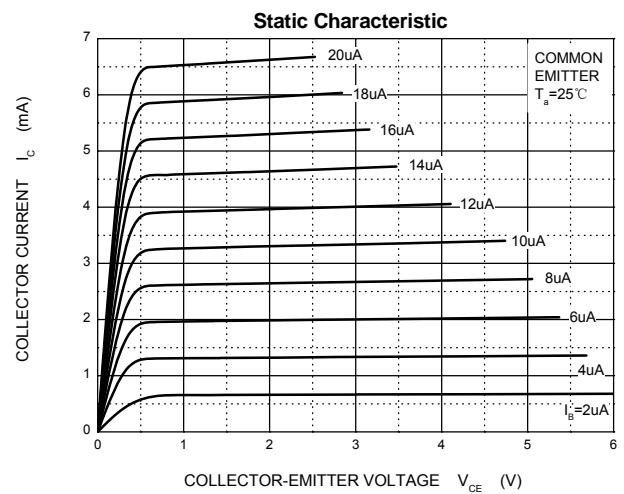


MAXIMUM RATINGS($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	6	V
I_c	Collector Current –Continuous	0.1	A
P_c	Collector Dissipation	200	mW
T_J	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55-150	°C

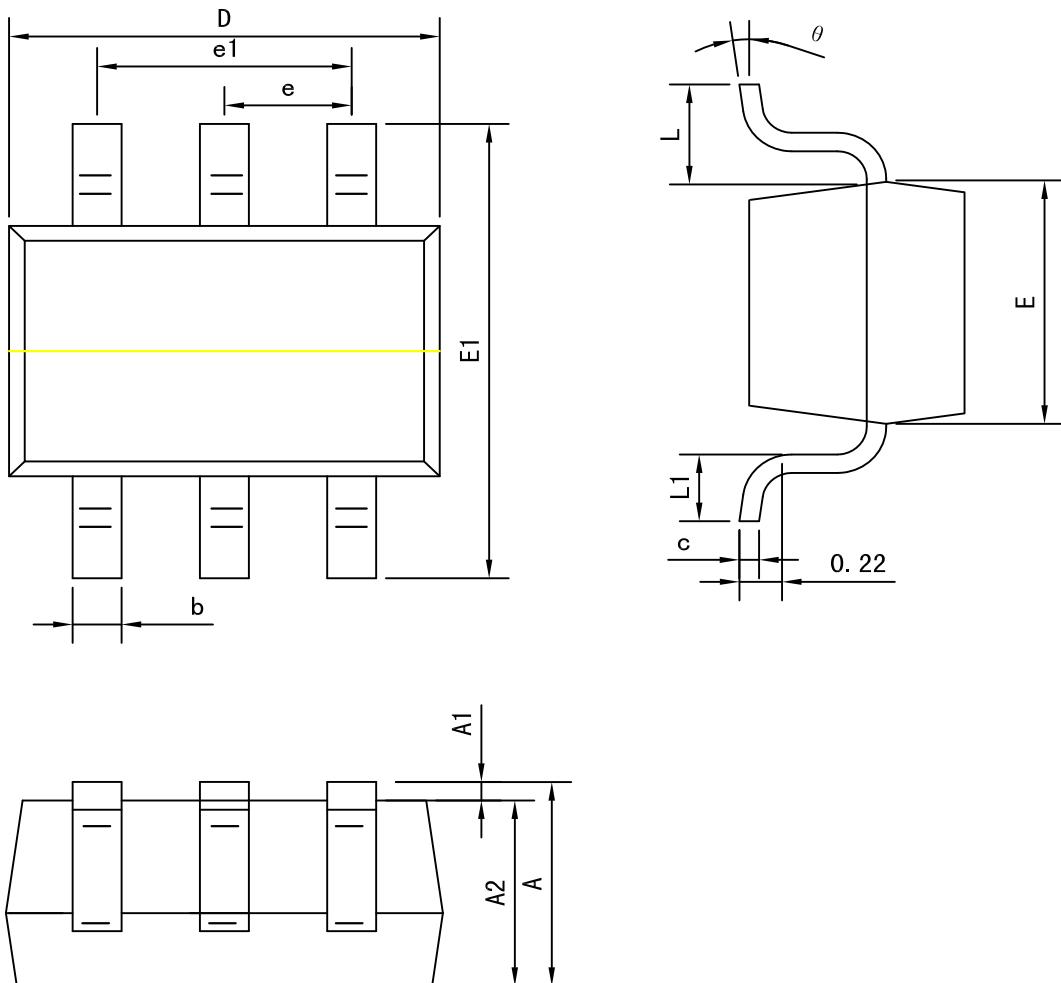
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$			15	nA
Emitter cut-off current	I_{EBO}	$I_C=0, V_{EB}=5\text{V}$			5	μA
DC current gain Group A			110		220	
	β		200		450	
	β	$V_{CE}=5\text{V}, I_C=2\text{mA}$	420		800	
Collector-emitter saturation voltage	$V_{CE(sat)(1)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.1	V
	$V_{CE(sat)(2)}$	$I_C=100\text{mA}, I_B=5\text{mA}$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.77		V
Transition frequency	f_T	$V_{CB}=5\text{V}, I_E=10\text{mA}, f=100\text{MHz}$	100			MHz
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			1.5	pF



Package outline dimensions

SOT-363



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
θ	0°	8°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Hong Kong Chuangji manufacturer:

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NJVMJD148T4G](#) [NTE123AP-10](#) [NTE153MCP](#) [NTE16](#)
[NTE195A](#) [NTE92](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SC2712S-GR,LF](#) [SP000011176](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC2412KT146S](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#) [MJE340](#) [Jantx2N5416](#) [US6T6TR](#) [NJL0281DG](#) [732314D](#) [CPH3121-TL-E](#)
[CPH6021-TL-H](#) [873787E](#) [IMZ2AT108](#) [MMST8098T146](#) [UMX21NTR](#) [MCH6102-TL-E](#) [NJL0302DG](#) [30A02MH-TL-E](#) [NTE13](#) [NTE26](#)
[NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [STX83003-AP](#) [JANTX2N2920L](#) [JANSR2N2222AUB](#) [CMLT3946EG TR](#) [2SA1371D-AE](#)